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Hex D-type Flip-Flops (with Clear)



ADE-205-460 (Z) 1st. Edition Sep. 2000

#### **Description**

This device contains 6 master-slave flip-flops with a common clock and common clear. Data on the D input having the specified setup and hold times is transferred to the Q output on the low to high transition of the clock input. The clear input when low, sets all outputs to a low state.

#### **Features**

• High Speed Operation:  $t_{pd}$  (Clock to Q) = 15 ns typ ( $C_L = 50 \text{ pF}$ )

High Output Current: Fanout of 10 LSTTL Loads

• Wide Operating Voltage:  $V_{CC} = 2$  to 6 V

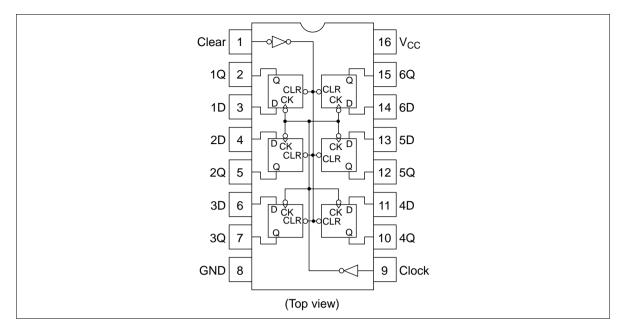
Low Input Current: 1 μA max

• Low Quiescent Supply Current:  $I_{CC}$  (static) = 4  $\mu$ A max (Ta = 25°C)

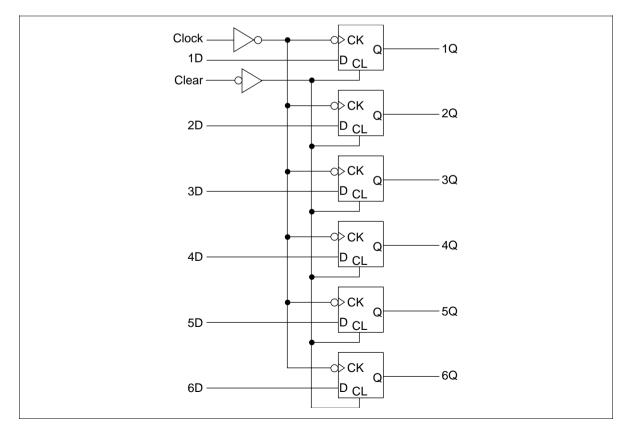
#### **Function Table**

Inputs			Outputs	
Clear	Clock	D	Q	
L	X	X	L	
Н	$\int$	Н	Н	
Н	$\int$	L	L	
Н	L	X	no change	
Н		X	no change	

## **Pin Arrangement**



## Logic Diagram



## RENESAS

## **DC** Characteristics

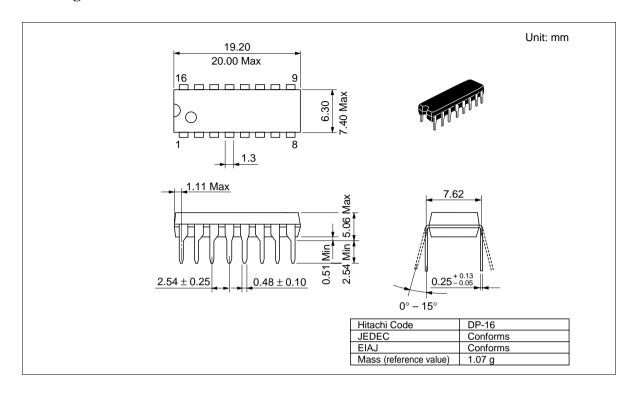
			Ta =	: 25°(	<b>:</b>	Ta = - +85°C	–40 to			
Item	Symbol	V <sub>cc</sub> (V)	Min	Тур	Max	Min	Max	Unit	Test Condition	าร
Input voltage	V <sub>IH</sub>	2.0	1.5	_	_	1.5	_	V		
		4.5	3.15	i —		3.15	_	_		
		6.0	4.2	_	_	4.2	_	_		
	V <sub>IL</sub>	2.0	_	_	0.5	_	0.5	V		
		4.5	_	_	1.35	_	1.35	_		
		6.0	_	_	1.8	_	1.8	=		
Output voltage	V <sub>OH</sub>	2.0	1.9	2.0	_	1.9	_	V	$Vin = V_{IH} \text{ or } V_{IL}$	$I_{OH} = -20 \mu A$
		4.5	4.4	4.5		4.4	_	_		
		6.0	5.9	6.0	_	5.9	_	_		
		4.5	4.18	-	_	4.13	_	=		$I_{OH} = -4 \text{ mA}$
		6.0	5.68	· —	_	5.63	_	=		$I_{OH} = -5.2 \text{ mA}$
	V <sub>OL</sub>	2.0	_	0.0	0.1	_	0.1	V	$Vin = V_{IH} \text{ or } V_{IL}$	I <sub>OL</sub> = 20 μA
		4.5	_	0.0	0.1	_	0.1	=		
		6.0	_	0.0	0.1	_	0.1	=		
		4.5	_	_	0.26	_	0.33	=		I <sub>OL</sub> = 4 mA
		6.0	_	_	0.26	_	0.33	=		I <sub>OL</sub> = 5.2 mA
Input current	lin	6.0	_	_	±0.1	_	±1.0	μΑ	Vin = V <sub>CC</sub> or GN	ND
Quiescent supply current	I <sub>cc</sub>	6.0	_	_	4.0	_	40	μА	Vin = V <sub>CC</sub> or GN	ND, lout = $0 \mu A$

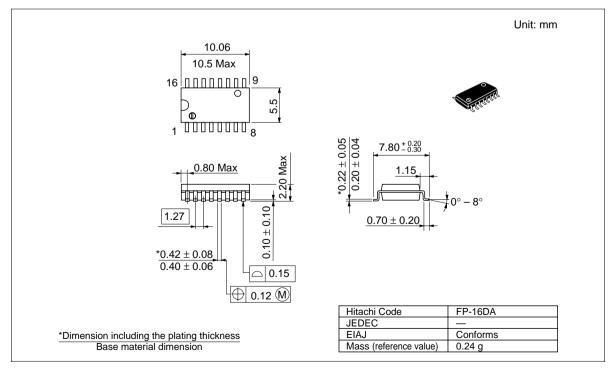
**AC Characteristics** ( $C_L = 50 \text{ pF}$ , Input  $t_r = t_f = 6 \text{ ns}$ )

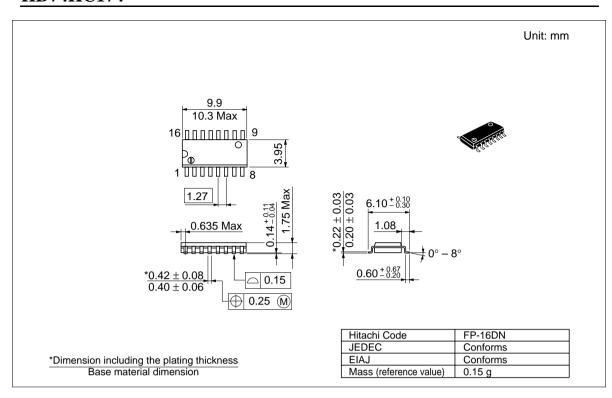
	Ta = -40  to
Ta = 25°C	+85°C

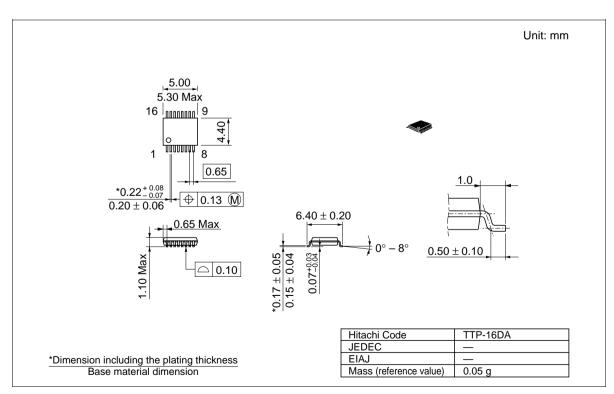
							_	
Symbol	V <sub>cc</sub> (V)	Min	Тур	Max	Min	Max	Unit	Test Conditions
f <sub>max</sub>	2.0	_	_	6	_	5	MHz	
	4.5	_	_	30	_	24	=	
	6.0	_	_	35	_	28	-	
t <sub>PLH</sub>	2.0	_	_	160	_	200	ns	Clock to Q
$t_{\tiny PHL}$	4.5	_	15	32	_	40	=	
	6.0	_	_	27	_	34	-	
	2.0	_	_	160	_	200	_	Clear to Q
	4.5	_	17	32	_	40	-	
	6.0	_	_	27	_	34	_	
t <sub>su</sub>	2.0	100	_	_	125	_	ns	Data to Clock
	4.5	20	3	_	25	_	_	
	6.0	17	_	_	21	_	_	
t <sub>h</sub>	2.0	5	_	_	5	_	ns	Clock to Data
	4.5	5	0	_	5	_	_	
	6.0	5	_	_	5	_	_	
t <sub>rem</sub>	2.0	25	_	_	31	_	ns	Clear to Clock
	4.5	5	-1	_	6	_	_	
	6.0	4	_	_	5	_	_	
t <sub>w</sub>	2.0	80	_	_	100	_	ns	Clock, Clear
	4.5	16	6	_	20	_	_	
	6.0	14	_	_	17	_	=	
t <sub>TLH</sub>	2.0	_	_	75	_	95	ns	
$t_{THL}$	4.5	_	5	15	_	19	=	
	6.0	_	_	13	_	16	=	
Cin	_	_	5	10	_	10	pF	
	f <sub>max</sub> t <sub>PLH</sub> t <sub>PHL</sub> t <sub>su</sub> t <sub>t</sub> t <sub>h</sub> t <sub>rem</sub>	$\begin{array}{c c} f_{\text{max}} & 2.0 \\ \hline 4.5 \\ \hline 6.0 \\ \hline t_{\text{PLH}} & 2.0 \\ \hline t_{\text{PHL}} & 4.5 \\ \hline 6.0 \\ \hline 2.0 \\ \hline 4.5 \\ \hline 6.0 \\ \hline t_{\text{su}} & 2.0 \\ \hline 4.5 \\ \hline 6.0 \\ \hline t_{\text{h}} & 2.0 \\ \hline 4.5 \\ \hline 6.0 \\ \hline t_{\text{rem}} & 2.0 \\ \hline 4.5 \\ \hline 6.0 \\ \hline \\ t_{\text{TLH}} & 2.0 \\ \hline t_{\text{TLH}} & 2.0 \\ \hline t_{\text{THL}} & 2.0 \\ \hline t_{\text{THL}} & 2.0 \\ \hline \end{array}$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$					

#### **Package Dimensions**









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